SENSITRON SEMICONDUCTOR

SHD626051 SHD626051P SHD626051N SHD626051D

TECHNICAL DATA DATA SHEET 4074, REV. H

HERMETIC SILICON CARBIDE RECTIFIER

DESCRIPTION: A 600-VOLT, 20 AMP POWER SILICON CARBIDE RECTIFIER IN A HERMETIC TO-257 PACKAGE AVAILABLE SCREENED TO ANY REQUIRED LEVEL

FEATURES:

- NO RECOVERY TIME OR REVERSE RECOVERY LOSSES
- NO TEMPERATURE INFLUENCE ON SWITCHING BEHAVIOR
- **High Frequency Option** Non-magnetic Glidcop leads are available for improved performance at high frequency; use part number prefix SHDG
- Ceramic Seal Option For ceramic seals use part number prefix SHDC
- Rohs Compliant Option For Rohs compliance, use suffix -G

MAXIMUM RATINGS

ALL RATINGS ARE @ T_C = 25 °C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	600	Volts
MAXIMUM DC OUTPUT CURRENT (With $T_c = 65 {}^{\circ}C$ for P and N suffixes)	Ιο	20	Amps
MAXIMUM DC OUTPUT CURRENT (With $T_c = 65 {}^{\circ}C$ for Single and D suffixes)	Ιο	10	Amps
MAXIMUM REPETITIVE FORWARD SURGE CURRENT PER LEG (t = 8.3ms, Sine) per leg, $T_c = 25$ °C	I _{FRM}	50	Amps
MAXIMUM POWER DISSIPATION, $T_c = 25 {}^{\circ}C$,	Pd	40	W
MAXIMUM THERMAL RESISTANCE, Junction to Case PER LEG	$R_{ extsf{ heta}JC}$	2.5	°C/W
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE*	Top, Tstg	-55 to 200	°C

* Note: SiC semiconductors will handle at or above this operating and storage temperature. However, extended operational use of the packaged device above 175C may reduce its future performance. All qualification testing and screening per MIL-PRF-19500 will only be performed to 175C.

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC		ΤΥΡ	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP	$T_J = 25^{\circ}C$	1.65	1.80	
Pulsed (I _f = 10 A PER LEG) V_f	T _J = 150 °C	2.05	2.20	Volts
MAXIMUM FORWARD VOLTAGE DROP	$T_J = 25^{\circ}C$	1.35	1.45	
Pulsed (I _f = 6 A PER LEG) V_f	T _J = 150 °C	1.60	1.70	Volts
MAXIMUM REVERSE CURRENT (Ir @ 600V PIV PER LEG)	T _J = 25 °C	0.04	0.15	
	T _J = 150 °C	0.08	0.50	mA
JUNCTION CAPACITANCE C_{T_j} (V _r =5V) per leg	C _T	250	350	pF
TOTAL CAPACITIVE CHARGE	Q _C per leg	35	N/A	nC
(V _R =600V I _F =20A di/dt=500A/ μ s T _J =25°C) This is design information only				

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MECHANICAL DIMENSIONS

PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER/COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER/COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER/DOUBLER (D)	ANODE	ANODE/ CATHODE	CATHODE

SCHEMATIC



Application Note: Customers should be aware that at the current stage of technical development of SiC, the reverse avalanche capabilities of the device are limited.

Customer designs will need to accommodate these limitations and avoid exposure of the device to this and other potentially damaging conditions in their applications.



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